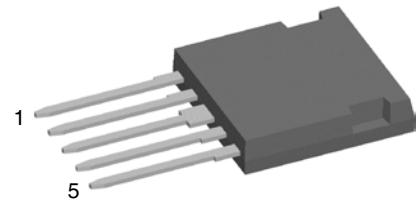
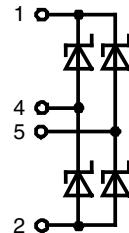


Silicon Carbide Schottky Rectifier Bridge in ISOPLUS i4-PAC™

V_{RRM} = 600 V
I_{dAVM} = 6.6 A
C_{junction} = 9 pF



Rectifier Bridge

| Symbol | Conditions | Maximum Ratings | | |
|-------------------|--|-----------------|--|---|
| V _{RRM} | | 600 | | V |
| I _{FAV} | T _C = 90°C; sine 180° (per diode) | 3 | | A |
| I _{DAVM} | T _C = 90°C | 6.6 | | A |
| I _{FSM} | T _C = 25°C; t = 10 ms; sine 50 Hz | 12 | | A |
| P _{tot} | T _C = 25°C (per diode) | 19 | | W |

| Symbol | Conditions | Characteristic Values | | | | |
|-------------------|-----------------------------------|--|------|------------|------|------------|
| | | (T _{VJ} = 25°C, unless otherwise specified) | min. | typ. | max. | |
| V _F | I _F = 4 A | T _{VJ} = 25°C T _{VJ} = 125°C | | 1.7 1.9 | 2.0 | V |
| I _R | V _R = V _{RRM} | T _{VJ} = 25°C T _{VJ} = 125°C | | 0.04 | 0.2 | mA mA |
| C _J | V _R = 400 V | T _{VJ} = 125°C | | 9 | | pF |
| R _{thJC} | | (per diode) | | 11.5 | 8 | K/W K/W |

Features

- Silicon Carbide Schottky Diodes
 - no reverse recovery at turn off
 - only charge of junction capacity
 - soft turn off waveform
 - no forward recovery at turn on
 - switching behaviour independent of temperature
 - low leakage current
- ISOPLUS i4-PAC™ package
 - isolated back surface
 - low coupling capacity between pins and heatsink
 - enlarged creepage towards heatsink
 - application friendly pinout
 - high reliability
 - industry standard outline

Applications

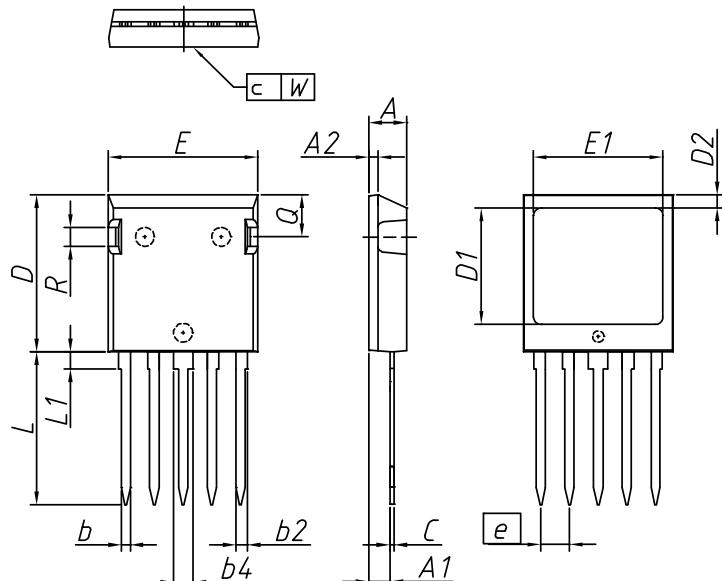
- output rectifiers of high end switch mode power supplies
- other high frequency rectifiers

Component

| Symbol | Conditions | Maximum Ratings | | |
|------------|--|-----------------|----|--|
| T_{VJ} | operating | -40...+175 | °C | |
| T_{stg} | | -40...+125 | °C | |
| V_{ISOL} | $I_{ISOL} \leq 1 \text{ mA}; 50/60 \text{ Hz}$ | 2500 | V~ | |
| F_c | mounting force with clip | 20 - 120 | N | |

| Symbol | Conditions | Characteristic Values | | |
|---------------|---|-----------------------|------|------|
| | | min. | typ. | max. |
| C_p | coupling capacity between shorted pins and mounting tab in the case | | 40 | pF |
| $d_s; d_A$ | pin - pin | 1.7 | | mm |
| $d_s; d_A$ | pin - backside metal | 5.5 | | mm |
| Weight | | 9 | | g |

Dimensions in mm (1 mm = 0.0394")



| DIM. | MILLIMETER | | INCHES | |
|------|------------|-------|--------|-------|
| | MIN | MAX | MIN | MAX |
| A | 4,83 | 5,21 | 0,190 | 0,205 |
| A1 | 2,59 | 3,00 | 0,102 | 0,118 |
| A2 | 1,17 | 2,16 | 0,046 | 0,085 |
| b | 1,14 | 1,40 | 0,045 | 0,055 |
| b1 | 1,47 | 1,73 | 0,058 | 0,068 |
| b2 | 2,54 | 2,79 | 0,100 | 0,110 |
| C | 0,51 | 0,74 | 0,020 | 0,029 |
| D | 20,80 | 21,34 | 0,819 | 0,840 |
| D1 | 14,99 | 15,75 | 0,590 | 0,620 |
| D2 | 1,65 | 2,03 | 0,065 | 0,080 |
| E | 19,56 | 20,29 | 0,770 | 0,799 |
| E1 | 16,76 | 17,53 | 0,660 | 0,690 |
| e | 3,81 | BSC | 0,15 | BSC |
| L | 19,81 | 21,34 | 0,780 | 0,840 |
| L1 | 2,11 | 2,59 | 0,083 | 0,102 |
| Q | 5,33 | 6,20 | 0,210 | 0,244 |
| R | 2,54 | 4,57 | 0,100 | 0,180 |
| W | - | 0,10 | - | 0,004 |

Die konvexe Form des Substrates ist typ. < 0,05 mm über der Kunststoffoberfläche der Bauteilunterseite

The convex bow of substrate is typ. < 0.05 mm over plastic surface level of device bottom side